High Power Laser Diode Bar



Part Number: BAR-107

High Power 19 Emitters Bar Multi-Mode Fabry-Perot CW Wavelength at 1470nm

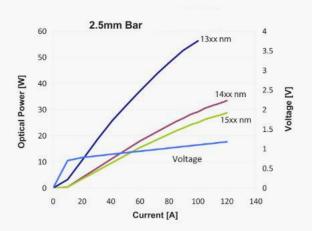


Features

- High Output Power
- High Dynamic Range
- High Efficiency
- Standard 19 Emitters Bar
- Cost Effective

Application

- Professional Medical
- Home Medical
- Laser Rangefinder





SemiNex delivers the highest available power at infrared wavelengths between 12xx and 19xx nm. When necessary, we will further optimize the design of our InP & GaSb laser chips to meet our customers' specific optical and electrical performance needs. Diodes, bars and packages are tested to meet customer and market performance demands. Typical results and packaging options are shown. Contact SemiNex for additional details or to discuss your specific requirements.

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High Power Laser Diode Bar



Specification

BAR-107



Optical	Symbol	Тур.	Units
Center Wavelength	λ _c	1470	nm (±20)
Output Power (CW)*	P _{out}	28	watts (±10%)
Chip Cavity Length	CL	2500	μm
Emitter Width	W	95	μm
Number of Emitters		19	
Spectral Width FWHM	Δλ	15	nm
Slope Efficiency	η	0.4	W/A
Fast Axis Div.	Θ⊥	25	deg FWHM
Slow Axis Div.	Θ	8	deg FWHM
Electrical	Symbol		Units
Power Conversion Eff.	η	30	%
Threshold Current	Ітн	12	Α
Operating Current	lop	100	Α
Operating Voltage	V _{op}	1	V
Mechanical		Range	Units
Operating Temp.**		-40 to 60	°C
Storage Temp.		-40 to 80	°C

*Specified values are rated at a constant heat sink temperature of 20°C.

**High temperature operation will reduce performance and MTTF.

Unless otherwise indicated all values are nominal.

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Mechanical Drawing



BAR ATTRIBUTES

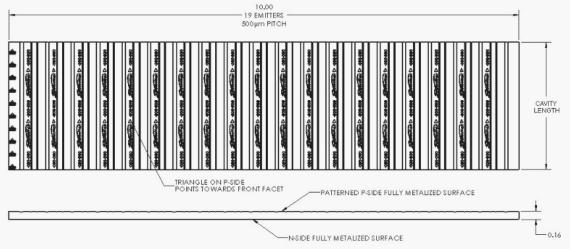
APERTURE WIDTH (µm)	Multi Mode (95) ± 3
BAR WIDTH (mm)	10 ± 0.01
THICKNESS (µm)	160 ± 10
CAVITY LENGTH (µm)	Varies ± 10

P METALIZATION

MATERIAL	THICKNESS (nm)	TOLERANCE (nm)
Ti	50	± 10
Pt	125	± 25
Au	250	± 50

N METALIZATION

MATERIAL	THICKNESS (nm)	TOLERANCE (nm)
Ti	30	± 10
Pt	125	± 25
Au	400	± 40



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